

1 Characteristics

Table 1. Absolute ratings (limiting values at 25 °C, unless otherwise specified)

Symbol	Parameter			Value	Unit
V _{RRM}	Repetitive peak reverse voltage			30	V
I _{F(RMS)}	Forward rms current			10	A
I _{F(AV)}	Average forward current, δ = 0.5, square wave	SMA	T _L = 135 °C	1	A
		SMA Flat Notch	T _L = 140 °C		
		SMB	T _L = 140 °C		
I _{FSM}	Surge non repetitive forward current	SMA	t _p = 10 ms sinusoidal	75	A
		SMA Flat Notch		90	
		SMB		75	
P _{ARM}	Repetitive peak avalanche power		t _p = 10 μs, T _j = 125 °C	110	W
T _{stg}	Storage temperature range			-65 to +150	°C
T _j	Maximum operating junction temperature ⁽¹⁾			+150	°C

1. $(dP_{tot}/dT_J) < (1/R_{th(j-a)})$ condition to avoid thermal runaway for a diode on its own heatsink.

Table 2. Thermal resistance parameter

Symbol	Parameter		Max. value	Unit
$R_{th(j-l)}$	Junction to lead	SMA	30	°C/W
		SMA Flat Notch	20	
		SMB	25	

For more information, please refer to the following application note :

- AN5088 : Rectifiers thermal management, handling and mounting recommendations

Table 3. Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Typ.	Max.	Unit
$I_R^{(1)}$	Reverse leakage current	$T_J = 25\text{ °C}$	$V_R = V_{RRM}$	-		200	μA
		$T_J = 100\text{ °C}$		-	6	15	mA
$V_F^{(1)}$	Forward voltage drop	$T_J = 25\text{ °C}$	$I_F = 1\text{ A}$	-		0.395	V
		$T_J = 125\text{ °C}$		-	0.260	0.300	
		$T_J = 25\text{ °C}$	$I_F = 2\text{ A}$	-		0.445	
		$T_J = 125\text{ °C}$		-	0.325	0.375	

1. Pulse test: $t_p = 380\text{ }\mu\text{s}$, $\delta < 2\%$

To evaluate the conduction losses, use the following equation:

$$P = 0.225 \times I_{F(AV)} + 0.075 \times I_{F(RMS)}^2$$

For more information, please refer to the following application notes related to the power losses :

- AN604: Calculation of conduction losses in a power rectifier
- AN4021: Calculation of reverse losses on a power diode

1.1 Characteristics (curves)

Figure 1. Average forward power dissipation versus average forward current

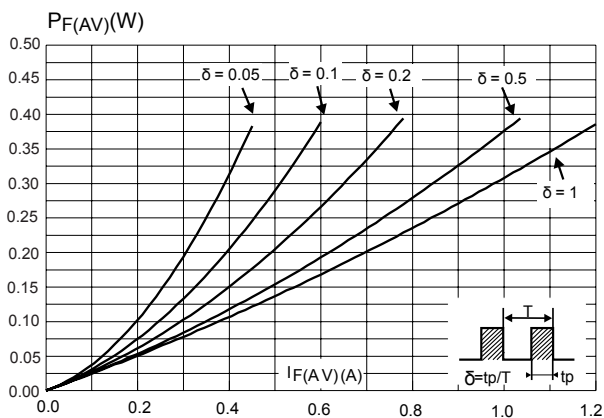


Figure 2. Average forward current versus ambient temperature ($\delta = 0.5$)

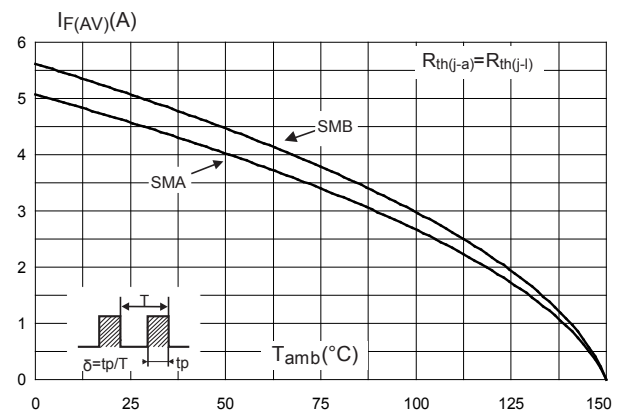


Figure 3. Normalized avalanche power derating versus junction temperature ($T_j = 125^\circ\text{C}$)

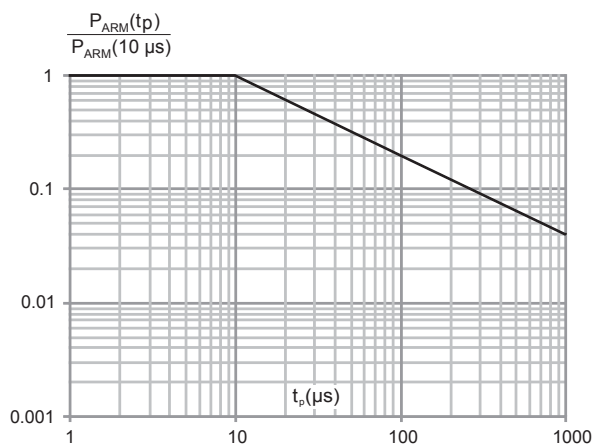


Figure 4. Relative variation of thermal impedance junction to ambient versus pulse duration (SMB)

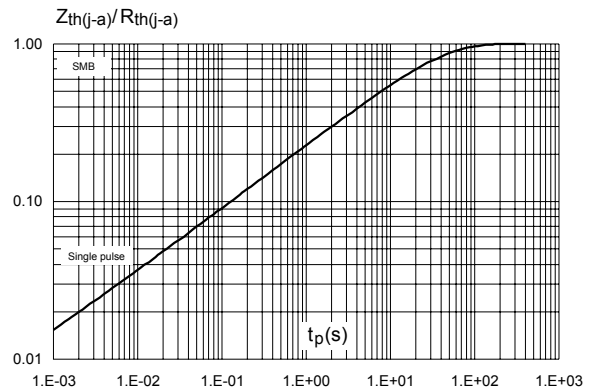


Figure 5. Relative variation of thermal impedance junction to ambient versus pulse duration (SMA)

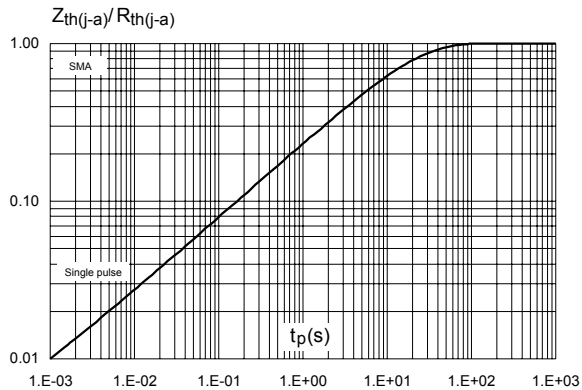


Figure 6. Reverse leakage current versus reverse voltage applied (typical values)

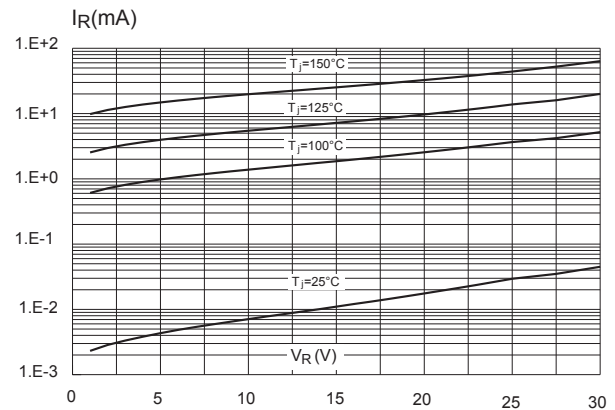


Figure 7. Junction capacitance versus reverse voltage applied (typical values)

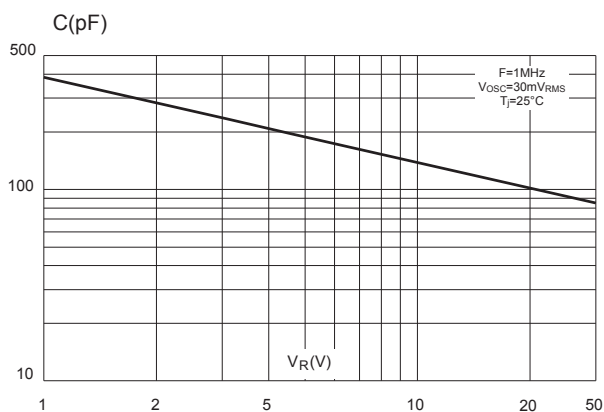


Figure 8. Forward voltage drop versus forward current (typical values, high level)

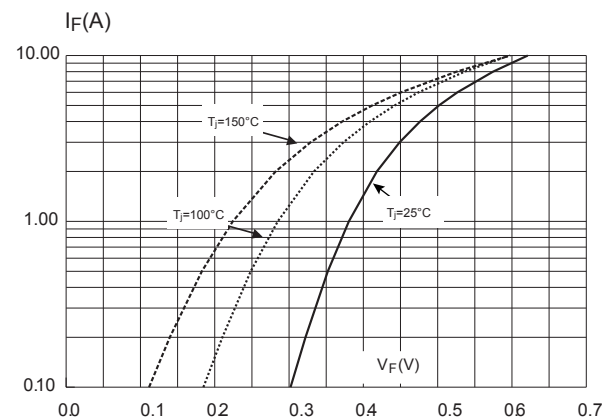


Figure 9. Forward voltage drop versus forward current (maximum values, low level)

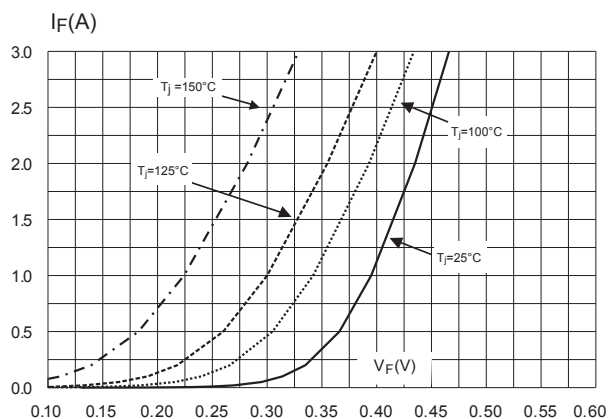


Figure 10. Thermal resistance junction to ambient versus copper surface under each lead (SMB)

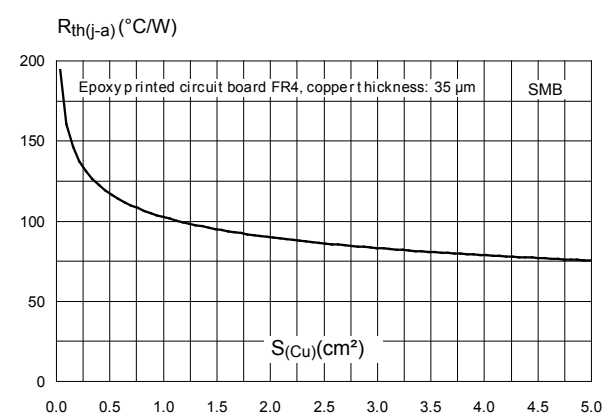


Figure 11. Thermal resistance junction to ambient versus copper surface under each lead (SMA)

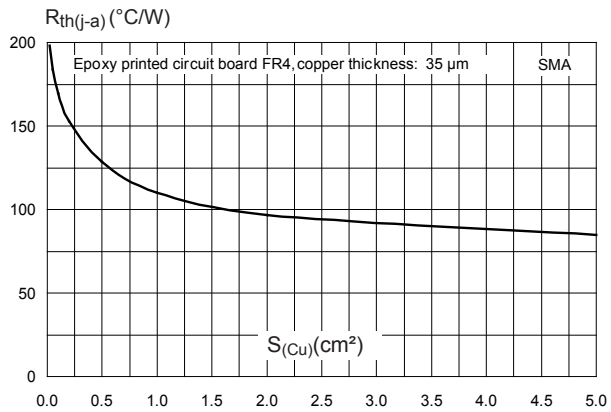
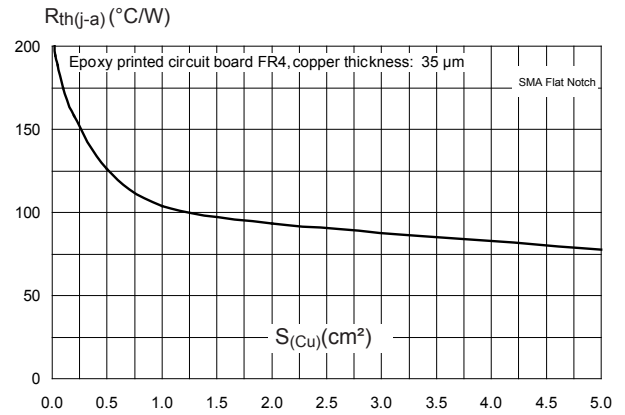


Figure 12. Thermal resistance junction to ambient versus copper surface under each lead (SMA Flat Notch)



2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of **ECOPACK** packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

2.1 SMA package information

- Epoxy meets UL94, V0
- Cooling method : by conduction (C)

Figure 13. SMA package outline

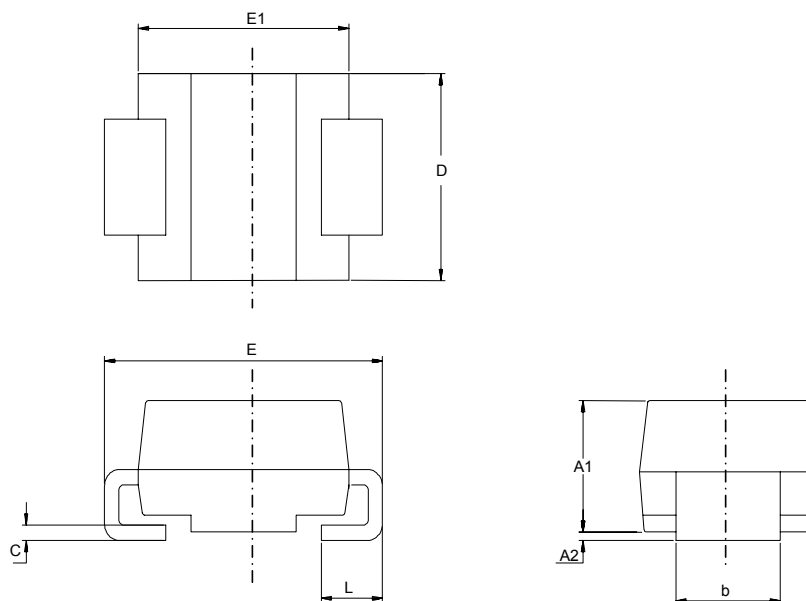
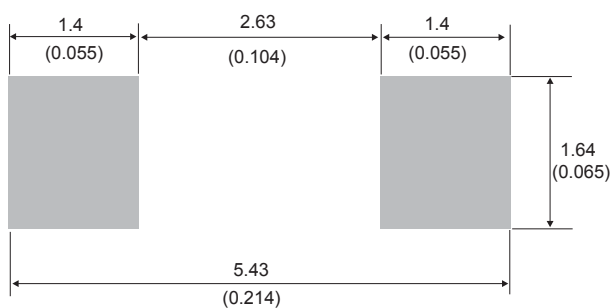


Table 4. SMA package mechanical data

Ref.	Dimensions			
	Millimeters		Inches (for reference only)	
	Min.	Max.	Min.	Max.
A1	1.90	2.45	0.074	0.097
A2	0.05	0.20	0.001	0.008
b	1.25	1.65	0.049	0.065
c	0.15	0.40	0.005	0.016
D	2.25	2.90	0.088	0.115
E	4.80	5.35	0.188	0.211
E1	3.95	4.60	0.155	0.182
L	0.75	1.50	0.029	0.060

Figure 14. SMA recommended footprint in mm (inches)



2.2 SMA Flat Notch package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Band indicates cathode

Figure 15. SMA Flat Notch package outline

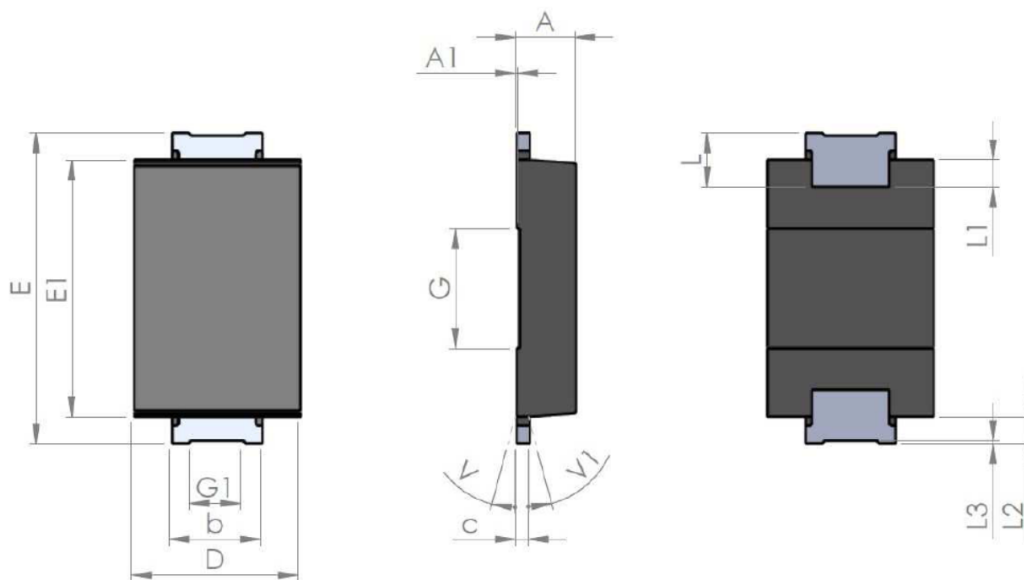
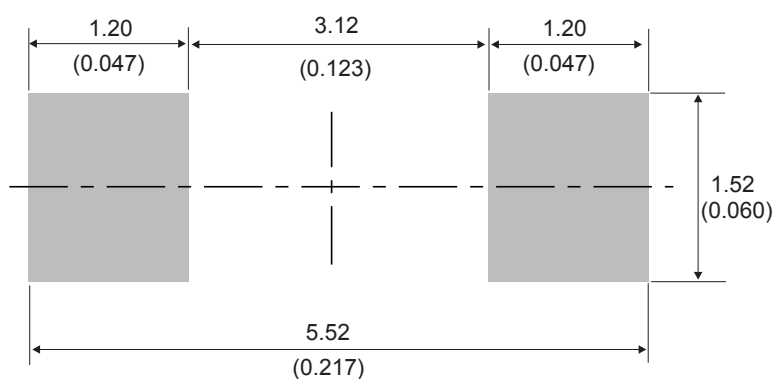


Table 5. SMA Flat Notch package mechanical data

Ref.	Dimensions					
	Millimeters			Inches (for reference only)		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A1	0.90		1.10	0.035		0.044
A1		0.05			0.002	
b	1.25		1.65	0.049		0.065
C	0.15		0.40	0.005		0.016
D	2.25		2.90	0.088		0.115
E	5.00		5.35	0.196		0.211
E1	3.95		4.60	0.155		0.182
G		2.00			0.079	
G1		0.85			0.033	
L	0.75		1.20	0.029		
L1		0.45			0.018	
L2		0.45			0.018	
L3		0.05			0.002	
V			8°			8°
V1			8°			8°

Figure 16. SMA Flat Notch recommended footprint in mm (inches)



2.3 SMB package information

- Epoxy meets UL94, V0
- Lead-free package

Figure 17. SMB package outline

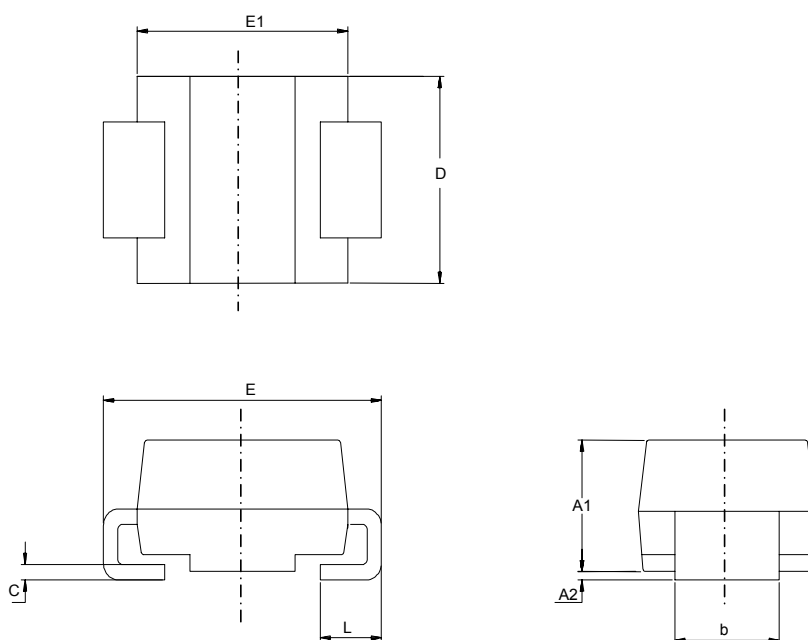
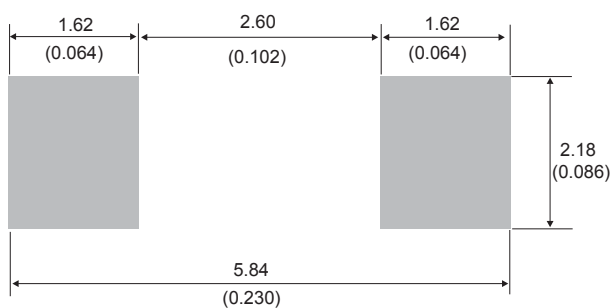


Table 6. SMB package mechanical data

Ref.	Dimensions			
	Millimeters		Inches (for reference only)	
	Min.	Max.	Min.	Max.
A1	1.90	2.45	0.074	0.097
A2	0.05	0.20	0.001	0.008
b	1.95	2.20	0.076	0.087
c	0.15	0.40	0.005	0.016
D	3.30	3.95	0.129	0.156
E	5.10	5.60	0.200	0.221
E1	4.05	4.60	0.159	0.182
L	0.75	1.50	0.029	0.060

Figure 18. SMB recommended footprint



3 Ordering Information

Table 7. Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
STPS1L30A	GB3	SMA	0.068 g	5000	Tape and reel
STPS1L30AFN	A13	SMA Flat Notch	0.039 g	10 000	Tape and reel
STPS1L30U	G23	SMB	0.107 g	2500	Tape and reel

Revision history

Table 8. Document revision history

Date	Version	Changes
Jul-2003	5A	Last update.
Aug-2004	6	SMA package dimensions update. Reference A1 max changed from 2.70 mm (0.106 inc.) to 2.03 mm (0.080 inc).
17-Sep-2018	7	Updated Table 1. Absolute ratings (limiting values at 25 °C, unless otherwise specified) and Figure 3. Normalized avalanche power derating versus junction temperature ($T_j = 125\text{ °C}$) .
26-Sep-2019	8	Added Section 2.2 SMA Flat Notch package information .

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